

RED DIODE LASER AT 635/637/640nm

RN-III-635L/637/640/1~200mW

产品描述

It features ultra compact design, long lifetime, cost-effectiveness and easy operation. They are widely used in measurement, spectrum analysis, laser lighting show, etc

产品参数

RN-III-635L/637/640/1~200mW			
Central wavelength (nm)	635±5	637±5	640±5
Operating mode	CW		
Output power (mW)	>1,10,20,..., 100		
Power stability (rms, over 4 hours)	<1%, <2%, <3%		
Transverse mode	Near TEM ₀₀		
M ² factor	<1.2		
Beam diameter at the aperture (1/e ² ,mm)	~1.2		
Beam divergence, full angle (mrad)	<1.0		
Polarization ratio	>50:1 (>100:1, optional) Horizontal±5 degree (Vertical Optional)		
Warm-up time (minutes)	<5		
Pointing stability after warm-up (mrad)	<0.05		
Beam height from base plate (mm)	24.8		
Operating temperature (°C)	10~35		
Power supply	85-264VAC	PSU-III-LED/ PSU-III-FDA (Frequency for 1Hz-30kHz)	
	100-240VAC	PSU-A-D (Frequency for 30kHz -100kHz)	
TTL / Analog modulation	TTL or Analog with 1Hz-1kHz 1kHz-10kHz, 10kHz-30kHz, 30kHz-100kHz optional		
Expected lifetime (hours)	10000		
Warranty	1 year		

